## EXCELITAS TECHNOLOGIES®

ENABLING THE FUTURE THROUGH LIGHT

Oct 18, 2022

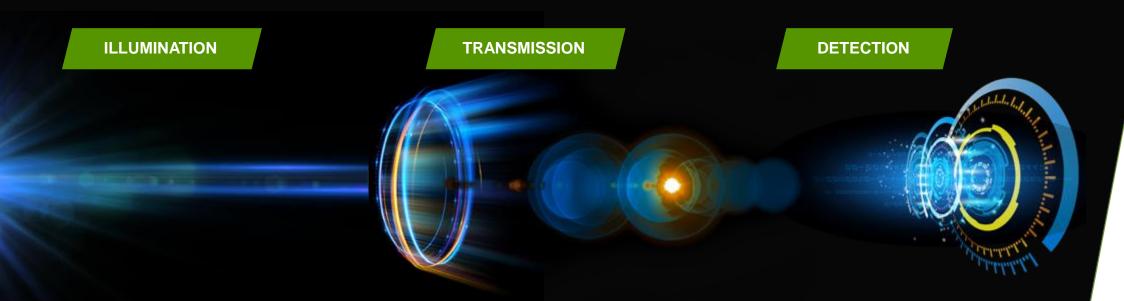
### VTH21 Series of Photodiodes Alpha Particle Detection for Radon Gas Detection Applications

Anand Pandy

Applications Engineering Leader, Detection



#### Your innovation partner for end-to-end photonic solutions



#### From source to sensor... and everything in between

- Illumination & Lasers
- Optics & Optomechanics
- Sensors & Detectors
- Electronics & Power
- Sophisticated Custom Integration



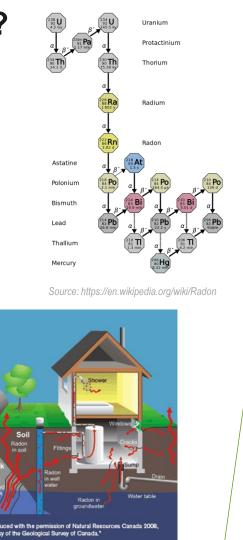
#### **Expanding Global Footprint**

- Headquartered in Waltham, MA USA
- 18 Photonic manufacturing centers
- 10 Administrative/Sales Offices



#### What is Radon? & Why Monitor Radon?

- Radon (Rn) is a radioactive inert gas
- colorless, odorless, tasteless
- EPA recognizes radon as leading cause of cancer among non-smokers
- Radon in an enclosed space, can accumulate to high concentrations and become a health concern
- Early radon detection is key to improve long-term health
- Connected Smart Home radon detector can provide continuous and early warning

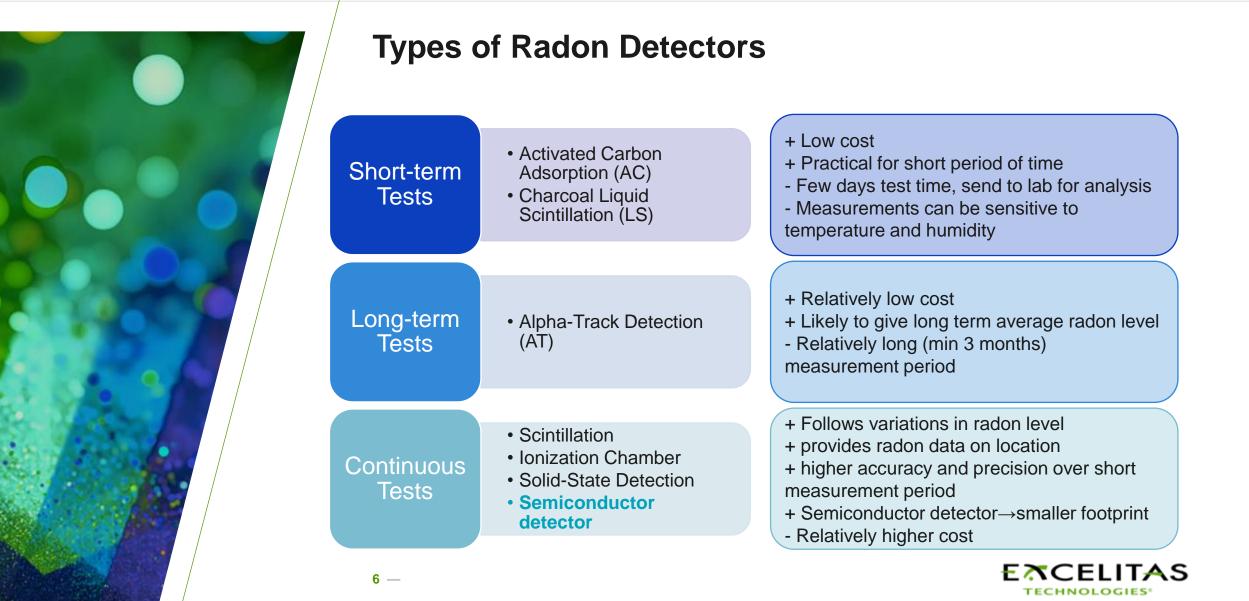








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#### Measurement requirements and Advantage of Si Detector

- Key requirements for detection of low radon concentration
  - Very long measurement time
  - Large detector area
  - Charge collection setup / channel volume
- Why Si PIN photodiode
  - Suitable for radiation detection, especially α particles
  - Good energy resolution
  - Large absorption depth for greater absorption
  - Continuous measurement
  - Ease of use
  - Low cost

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Excelitas New Radon Detection Photodiodes





### **Excelitas VTH21 Series Photodiodes**

- Direct detection of alpha particles
- Large active area for higher detection probability
- Wide operating voltage range
- Low capacitance
- Low dark current

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- High reliability for "open air" detection (unsealed detector)
- Two active area sizes 5 mm x 5 mm and 10 mm x 10 mm



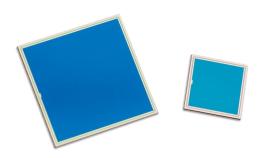
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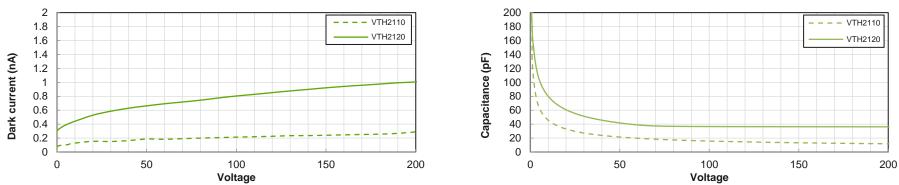


#### **Key Specifications**

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		Chip ID:	5 mm	10 mm	
Parameter	Symbol	Conditions			Unit
Breakdown voltage	V <sub>BR</sub>	100 uA	> 100	> 100	V
Junction capacitance	C	20 V	< 30	< 120	рF
Dark current	I <sub>D</sub>	20V	< 2	< 5	nA
		40 V	< 5	< 10	nA
Depletion layer thickness	t	20 V	> 0.09	> 0.09	mm
Dead layer	t <sub>d</sub>	Si equivalent	< 150	< 150	nm





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## **Questions?**



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